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Cds-coated TiO$_2$ nanotube layers: downscaling tube diameter towards efficient heterostructured photo-electrochemical conversion

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Novel heterostructured solar cell based on TiO$_2$ nanotube layers uniformly coated by CdS thin layer (using ALD) is presented. Downscaling the nanotube diameter (95 to 35 nm) enhanced twice the UV and VIS light photocurrents. Further photocurrent improvement resulted from prior annealing of TiO$_2$ nanotube layers from 300 to 600°C.

Every increasing demand for the long-term replacement of fossil fuels by low-cost, high-efficient, renewable and environmentally friendly sources of energy led photovoltaic technologies encounter a tremendous development to meet this target. Next to silicon technologies encounter a tremendous development to meet this target. Next to silicon technologies, the offer the advantage of directed charge transport and controlled phase separation between donor and acceptor parts of the solar cell and thus ensure best possible TiO$_2$ - chromophore interface, especially for high-aspect ratio nanotubes.

Herein, we present photo-electrochemical and structural characterization of a new type of heterostructured photochemical half-cells, fabricated using highly ordered n-type conductive TiO$_2$ nanotubular scaffolds with different diameters (35, 56, 95 nm) coated by CdS (40 cycles, thickness ~6 nm) deposited via a tailored ALD process.

The TiO$_2$ nanotube layers used in our experiments were prepared by anodization of Ti foils. The anodization conditions for these layers with similar thicknesses and different nanotube inner diameters were described previously. Prior to deposition of CdS, amorphous nanotube layers were converted to anatase/rutile modifications by the annealing protocol applied previously in the range of temperatures from 300 to 600 °C.

In the second step, TiO$_2$ nanotube layers were coated for the first time by CdS by ALD (TFS200, Beneq) using following conditions. The dimethylcadmium (electronic grade 99.999%) and gaseous H$_2$S were used as the cadmium precursor and the sulphur source, respectively. High purity nitrogen (99.9999%) was the carrier and purging gas at a flow rate of 400 standard cubic centimetres minute (sccm). Under these deposition conditions, one growth ALD cycle was defined by the following sequence: dimethylcadmium pulse (400ms)-N$_2$ purge (10s)-H$_2$S pulse (1s)-N$_2$ purge (15s). The TiO$_2$ nanotube layers were CdS-coated at 150 °C applying 40 ALD cycles. This corresponds to the nominal thickness of approx. 6 nm, as confirmed by variable angle spectroscopic ellipsometry (VASE® ellipsometer, J.A. Woollam, Co., Inc.) of CdS coatings on Si wafers. The composition of CdS deposited by ALD on a Si wafer was verified using XPS which showed the Cd:S ratio to be 1:1. The morphology of the TiO$_2$ nanotube layers were characterized by a field-emission SEM (FE SEM JEOL JSM 7500F) and a high-resolution field-emission scanning electron microscope (FE SEM JEOL JSM 7610F).
resolution TEM (HRTEM, FEI Titan) equipped with STEM mode and EDX mapping.

Fig. 1 shows top-view SEM images of blank TiO$_2$ annealed (400°C) nanotube layers with different average nanotube diameters: A) 35 nm, B) 56 nm, C) 95 nm. The SEM images D-F represent top-view images of corresponding TiO$_2$ nanotube layers coated with CdS by ALD. One can see an obvious increase of the wall thicknesses and thus smaller inner nanotube diameters between blank and coated nanotube layers which unequivocally indicates on the presence of the CdS coating. In order to demonstrate that the TiO$_2$ nanotube layers with different diameters are homogeneously coated with CdS throughout the whole thickness of all layers (approx. 600 nm), cross-sectional SEM analyses of CdS coated nanotube layers were carried out. These analyses verified that the nanotubes are indeed well coated from the top to the bottom part and as well within interiors and exteriors for all nanotube layers. Representative cross-sectional SEM images are shown as insets in Fig. 1.

It was supposed that the significant increase of the number of nanotubes per cm$^2$ may have the potential to enhance the photocurrent response of heterostructured solar cells due to the increase of the interfacial surface area between the chromophore (produced as conformal coating by ALD) and the TiO$_2$ nanotube layers. The estimated overall surface areas by simple calculations per 1 cm$^2$ of TiO$_2$ nanotube layer for the used TiO$_2$ nanotube layers are: 52, 29 and 23 cm$^2$ / cm$^2$ of the macroscopic geometrical area for 35, 56 and 95 nm inner diameters of TiO$_2$ nanotubes, respectively.

In order to obtain information about the photoelectrochemical properties of the nanotube layers and the CdS-coated TiO$_2$ nanotube layer heterostructures, photocurrent measurements were carried out in an aqueous electrolyte containing 0.1 M Na$_2$SO$_4$ employing a photoelectric spectrophotometer (Instytut Fotonowy) in the wavelength range 300 – 650 nm at 0.4 V vs Ag/AgCl reference electrode. Apparently, the coupling of CdS coatings with TiO$_2$ nanotube layers causes a strong sensitizing effect, as shown in Fig. 2. Firstly, the photocurrent density under UV light is enhanced several times as compared to blank TiO$_2$ nanotube layers. We believe that this phenomenon is related to the annihilation of surface states during ALD of CdS which significantly improves the charge collection efficiency, as demonstrated in previous works. More importantly, a robust photocurrent density can be observed in the visible spectral range, peaking at a wavelength of 470 nm. The recorded incident photon-to-electron conversion efficiencies (IPCE) that are shown in Fig. 2B are significantly higher than values reported previously for chalcogenide sensitized TiO$_2$ nanotube layers by chemical bath deposition, spincoating, and electrodeposition, due the fact that the ALD coating of CdS leads to the largest possible interfacial contact area with TiO$_2$ nanotube layers from these techniques.

A) photocurrent density B) incident photon-to-electron conversion efficiency C) and D) photocurrent transients at 340 nm and 470 nm, respectively, recorded for anatase TiO$_2$ nanotube layers annealed at 400°C with different diameters sensitized with crystalline CdS films deposited by ALD.

Fig. 1 G and H show STEM image and EDX map, respectively, of the CdS-coated nanotube shown in Fig. 1 F. Evidently, the Cd species (forming CdS) are present all along the TiO$_2$ nanotube, in line with the expectation of uniform ALD coating.

Fig. 2 A) photocurrent density B) incident photon-to-electron conversion efficiency C) and D) photocurrent transients at 340 nm and 470 nm, respectively, recorded for anatase TiO$_2$ nanotube layers annealed at 400°C with different diameters sensitized with crystalline CdS films deposited by ALD.
In addition, we found that the collected photocurrent density increased approximately by a factor of 2 with downsizing of the TiO$_2$ nanotube diameter from 95 to 35 nm in the spectral range from 300 to 500 nm. This result perfectly coincides with the increased active surface area of TiO$_2$ nanotube layers in the same range of nanotube diameters. Thus, our findings well corroborate with the assumption that an increase of the interfacial surface area between the chromophore and the TiO$_2$ nanotube layers should generate higher photocurrent density due to a larger amount of the CdS absorber deposited by ALD. Conclusively, the combination of 1D nanostructured TiO$_2$ nanotube layers with a thin light absorber deposited by ALD opens a door for a new approach for fabrication of efficient novel hybrid solar cells. For the energy diagram of CdS / TiO$_2$ heterostructure, we refer to previously published literature.$^{29,30}$

Further, we investigated the influence of thermal treatment of uncoated TiO$_2$ nanotube layers on the photoresponse of subsequently prepared heterostructures based on CdS-coated TiO$_2$ nanotube layers. For this experiment, we selected nanotube layers with the inner diameter of 35 nm, since they have demonstrated the highest IPCE in the whole spectral range (300-650 nm). One can see from Fig. 3 A and B that IPCE of CdS-coated TiO$_2$ heterostructures increased with increasing temperature of prior annealing of TiO$_2$ nanotube layers in the range of temperatures from 300 to 600 °C.

The enhancement in IPCE is not linear with rising temperature and can be divided into 3 steps. The most intensive improvement in IPCE was observed when TiO$_2$ nanotube layers were pre-annealed from 300 to 400 °C. Next, it seems that annealing of TiO$_2$ nanotube layers at 400 and 500 °C has a similar effect while annealing at 600 °C, which leads to the anatase to rutile transition,$^{29}$ adds further contribution to IPCE. In order to obtain a deeper understanding of this phenomenon, we collected FE-SEM top-view images of the CdS-coated TiO$_2$ nanotube layers (see Fig. 3 C to F) in combination with X-ray diffraction (see Fig. 4). At first sight, one can see that the level of TiO$_2$ nanotube layer coverage by CdS is noticeably different. While the TiO$_2$ nanotube layers pre-annealed at 300 °C are decorated with CdS nanoparticles as demonstrated in Fig. 3C, a compact and uniform CdS crystalline coating was formed on TiO$_2$ nanotube layers pre-annealed at 400, 500 and 600 °C (see Fig. 3 D to F). These results indicate that the CdS deposition on TiO$_2$ nanotubes via ALD strongly depends on the TiO$_2$ crystallinity. In the case of TiO$_2$ nanotube layers pre-annealed at 300°C, the incubation time for the CdS nucleation seems to be longer than for all other samples pre-annealed at higher temperatures. As a consequence of that, these TiO$_2$ nanotube layers are only decorated by CdS nanoparticles leading to lower total mass of CdS and thus lower IPCE. Since it is evident from XRD that the background in the range of 2 theta from 10 to 22° has different shape for this particular TiO$_2$ nanotube layer pre-annealed at 300 °C indicating the presence of an amorphous phase, one may assume that the CdS nanoparticle growth can be attributed to the incomplete transformation of originally amorphous TiO$_2$ nanotubes to the anatase phase. On the other hand, TiO$_2$ nanotube layers pre-annealed at higher temperatures template the crystal growth of CdS which corresponds to the well evolved crystals. Overall, these findings corroborate well with literature that shows that different crystallinity of substrates used for ALD leads to different ALD deposition progress.$^{33,34}$

![Fig. 3](image)

**Fig. 3** A) photocurrent density B) incident photon-to-electron conversion efficiency (IPCE) recorded for of anatase TiO$_2$ nanotube layers with 35 nm inner diameter annealed at 300, 400, 500 and 600 °C and sensitized with crystalline CdS films by ALD. C) to F) represent top view SEM images of CdS-coated TiO$_2$ nanotube layers annealed at: C) 300 °C, D) 400 °C, E) 500 °C and F) 600 °C.

![Fig. 4](image)

**Fig. 4** Bragg diffractions of TiO$_2$ nanotube layers with 35 nm inner diameter annealed at 300, 400, 500 and 600 °C and sensitized with crystalline CdS films deposited by ALD (left panel). The HRTEM image of the TiO$_2$ nanotube layer pre-annealed at 400°C coated with CdS (right panel).

The templating effect is obvious as well from the XRD patterns and the HRTEM image. CdS crystallizes in the hexagonal phase within the space group P6$_3$mmc$^{29}$ and lattice parameters $a = 4.16$ Å, $c = 6.68$ Å. Both the anatase and the rutile modifications
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Posess one cubic face with lattice parameters a = 3.78 Å (space group I4/1/amd) and a = 4.59 Å (space group P4_3/mmm) which results in lattice mismatch with CdS 10% and 10.4%, respectively. Since the lattice mismatch between CdS and TiO_2 phases is small, the nucleation and subsequent crystal growth can proceed fast. From XRD patterns, one can see that CdS crystallizes with the preferential orientation along the crystallographic plane (002) which is more pronounced with increasing the pre-annealing temperature of TiO_2 nanotube layers. This observation also supports the idea that fully crystalline TiO_2 nanotube layers pre-annealed at temperatures at about 400 °C are suitable matrices for the ALD deposition of uniform CdS coatings.

Conclusions

We presented photo-electrochemical results for anodic TiO_2 nanotube layers grown with different diameter sizes (35, 56 and 95 nm) with a thickness of approx. 600 nm sensitized with 6 nm thick CdS coatings deposited by ALD. We found that the collected photocurrents increased approximately by a factor of 2 with downsampling of the TiO_2 nanotube diameter from 95 to 35 nm in the spectral range from 300 to 500 nm. The result perfectly coincides with the increased active surface area of TiO_2 nanotube layers in the same range of nanotube diameters. We also demonstrated the effect of annealing temperature of TiO_2 nanotube layers on the photocurrent generation of the CdS-coated TiO_2 nanotube layer photochemical cell. This study unequivocally showed that nanotube layers pre-annealed at temperatures higher than 400 °C generated higher photocurrent density in the spectral range from 350-550 nm than nanotube layers pre-annealed at 300 °C due to the presence of amorphous phase. Last but not least, we showed the added value of ALD for uniform coating of nanotube layers by functional secondary material.

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Notes and references

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